



DMN2005UPS

20V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI[®]

Product Summary

V _{(BR)DSS}	Rds(on)	Ι _D T _C = +25°C	
20V	4.6mΩ @ V _{GS} = 4.5V	100A	
200	8.7mΩ @ V _{GS} = 2.5V	80A	

Description

This new generation P-Channel Enhancement Mode MOSFET has been designed to minimize $R_{DS(ON)}$ and yet maintain superior switching performance. This device is ideal for use in Notebook battery power management and Loadswitch.

Applications

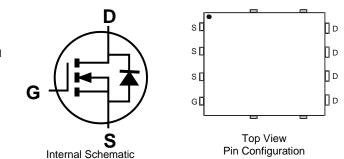
- Motor Control
- DC-DC Converters
- Power Management

Features

- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: POWERDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2005UPS-13	POWERDI [®] 5060-8	2,500 / Tape & Reel

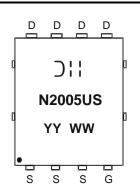
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



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POWERDI[®]5060-8





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 6) V_{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	I _D	20 15	А
Continuous Drain Current (Note 6) V_{GS} = 10V	Steady State	T _C = +25°C T _C = +70°C	ID	100 88	A
Pulsed Drain Current (380µs Pulse, Duty Cycle = 19		I _{DM}	150	A	
Maximum Continuous Body Diode Forward Current (Mounted on Infinite Heatsink)			ls	150	A
Avalanche Current (Note 7) L=0.2mH			I _{AS}	36	A
Avalanche Energy (Note 7) L=0.2mH			E _{AS}	133	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.5	W
Thermal Desistance, Junction to Ambient (Note 5)	Steady state	P	98	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ extsf{ heta}JA}$	83	
Total Power Dissipation (Note 6)		PD	3.0	W
Thermal Desistance, Junction to Ambient (Note 6)	Steady state	P	51	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ extsf{ heta}JA}$	43	
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.5		
Operating and Storage Temperature Range		TJ. TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	—	1	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)	•						
Gate Threshold Voltage	V _{GS(TH)}	0.4	0.7	1.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	D	_	_	4.6	mΩ	V _{GS} = 4.5V, I _D = 13.5A	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	—	8.7	11177	$V_{GS} = 2.5V, I_D = 13.5A$	
Diode Forward Voltage	V _{SD}	_	0.8	1.1	V	$V_{GS} = 0V, I_{S} = 27A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	_	5337	-	pF		
Output Capacitance	Coss	—	560	-	pF	$V_{DS} = 10V, V_{GS} = 0V,$ - f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	—	505	_	pF		
Gate Resistance	Rg	—	0.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	60	—	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	—	142	—	nC		
Gate-Source Charge	Q _{gs}	—	7	—	nC	V _{DS} = 16V, I _D = 27A	
Gate-Drain Charge	Q _{gd}	—	11	—	nC		
Turn-On Delay Time	t _{D(ON)}	_	12.4	_	ns		
Turn-On Rise Time	t _R	—	29.8	_	ns	V _{GS} = 5V, V _{DS} = 10V,	
Turn-Off Delay Time	t _{D(OFF)}	_	117	_	ns	R _G = 4.7Ω, I _D = 13.5A	
Turn-Off Fall Time	t _F	—	52	_	ns		
Body Diode Reverse Recovery Time	t _{RR}	—	17.8	_	ns	I _F = 13.5A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q _{RR}	—	8.6	_	nC	I _F = 13.5A, di/dt = 100A/µs	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_{J} = +25°C.

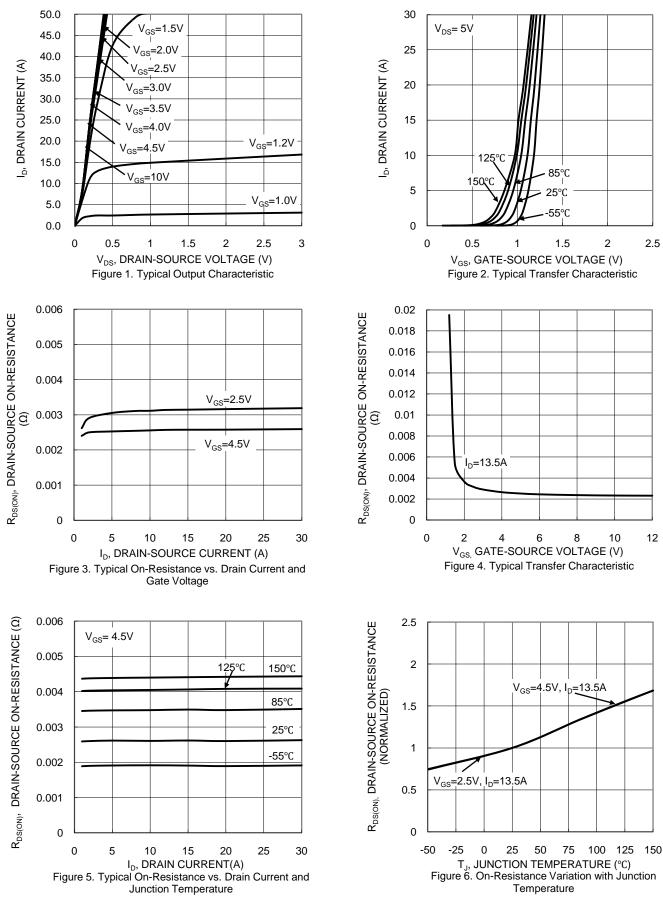
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

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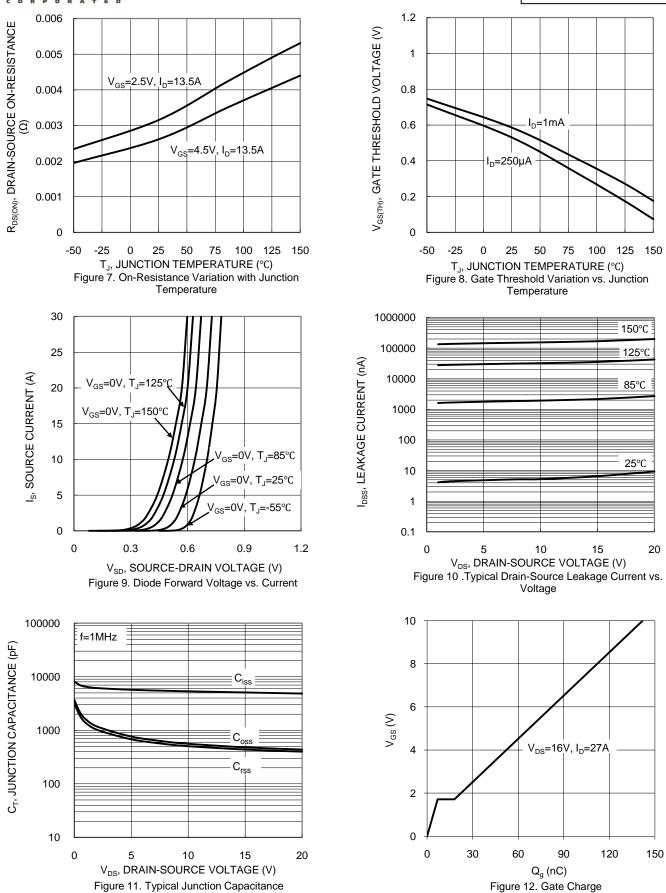


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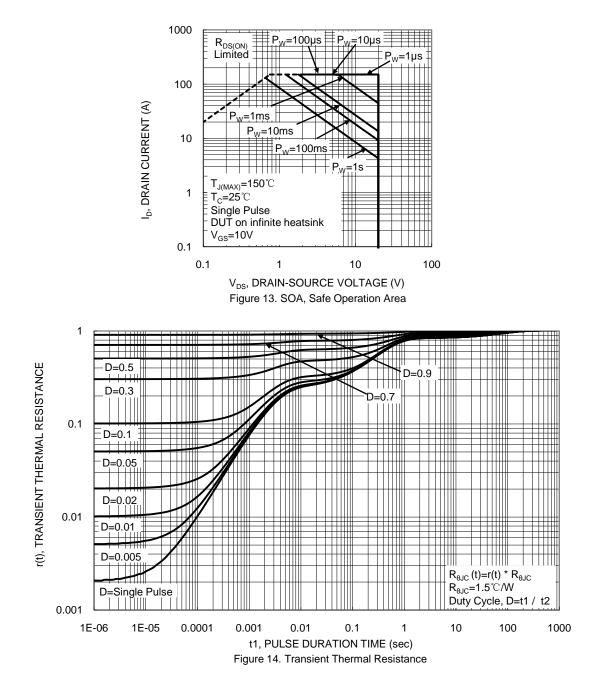
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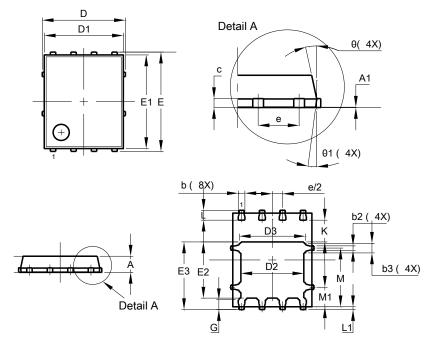


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Package Outline Dimensions

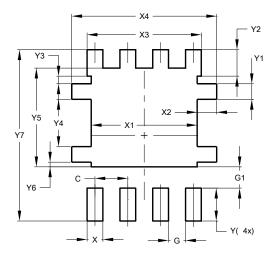
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



POWERDI [®] 5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	(6.15 BSC			
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
θ	10º	12º	11º		
θ1	6º	8º	7°		
Al	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

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